TOSHIBA Photocoupler IRED & Photo IC

TLP550

Microprocessor System Interfaces
Digital Logic Ground Isolation
Line Receiver
Switching Power Supply Feedback Control
Transistor Inverter

TLP550 consists of a high-output infrared emitting diode and a one chip photo diode– transistor.

TLP550 has no base connection, and is suitable for application at noisy environmental condition.

This unit is 8-lead DIP package.

- Isolation voltage : 2500 Vrms (min)
- Propagation delay time (t_{pHL} / t_{pLH}):

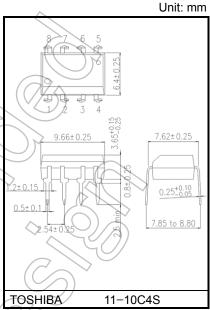
 $t_{pHL} = 0.5 \mu s$ (typ.),

 $t_{pLH} = 0.6\mu s$ (typ.)

 $(RL=1.9 k\Omega)$

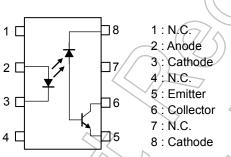
- TTL compatible
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

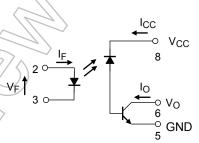


Weight: 0.54 g (typ.)

Pin Configuration (top view)



Schematic



Start of commercial production 1981-09

Current Transfer Ratio

Classification		sfer Ratio (%) /I _F)	Marking of Classification
	Min	Max	
(None)	10	_	Blank, O, Y
Rank O	19	_	0
Rank Y	35	_	Υ

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	(Note 1)	(F	25	mA
	Pulse forward current	(Note 2)	(FP	50	mA
LED	Peak transient forward current	(Note 3)	IFPT	1	A
	Reverse voltage		VR	5	\\
	Diode power dissipation	(Note 4)	PD	45	mW
	Output current		0	8	mΑ
or	Peak output current	200	IOP	16	mA
Detector	Supply voltage	9(0)	Vcc	0.5 to 15	V
Ď	Output voltage		Vo	-0.5 to 15	V
	Output power dissipation	(Note 5)	Po)) 100	mW
Ope	rating temperature range		Topr	-55 to 100	°C
Stor	rage temperature range	\rightarrow	T _{stg}	−55 to 125	°C
Lea	d solder temperature (10 s)		T _{sol}	260	°C
Isola	ation voltage (AC, 60 s, R.H. ≤ 60 %)	(Note 6)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Derate 0.8mA above 70 °C.

(Note 2) 50 % duty cycle, 1 ms pulse width. Derate 1.6 mA / °C above 70 °C.

(Note 3) Pulse width 1 µs, 300 pps.

(Note 4) Derate 0.9 mW / °C above 70 °C.

(Note 5) Derate 2 mW / °C above 70 °C.

(Note 6) Device considered two-terminal device: Pins 1, 2, 3 and 4 shorted together and pin 5, 6, 7 and 8 shorted together.



Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 16 mA	1.45	1.65	1.85	V
	Forward voltage temperature coefficient	ΔV _F / ΔTa	IF = 16 mA	-	-2	1	mV / °C
	Reverse current	I _R	V _R = 5 V	/	_	10	μΑ
	Capacitance between terminal	Ст	V _F = 0 V, f = 1 MHz		60	-	pF
	High level output current	IOH (1)	IF = 0 mA, V _{CC} = V _O = 5.5 V		3	500	nA
		IOH (2)	I _F = 0 mA, V _{CC} = V _O = 15 V	<u> </u>	_	5	
etector		Іон	I _F = 0 mA, V _{CC} = 15 V V _O = 15 V, Ta = 70 °C	2	_	50	μА
De	High level supply voltage	Іссн	IF = 0 mA, V _{CC} = 15 V	_	0.01	1	μΑ
	Supply voltage	Vcc	ICC = 0.01 mA	15		_	V
	Output voltage	Vo	I _O = 0.5 mA	15	46	\rightarrow	V

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
		I _E = 16 mA,		40	_	
	(Vcc = 4.5V, Rank O	19	40		
Current transfer ratio	la /la	Vo = 0.4 V Rank Y	35	50	_	%
Current transfer ratio	10 / IE/	I _F = 16 mA, V _{CC} = 4.5 V,	5	_	-	70
		V _O = 0.4 V, Ta = 0 to 70°C Rank O, Y	15	_	_	
Low level output voltage	Vol	I _F = 16 mA, V _{CC} = 4.5 V, I _O = 1.1 mA (Rank O: I _O = 2.4 mA)	_	_	0.4	٧

Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input-output) (Note 7)	Cs	V _S = 0 V, f = 1 MHz	-	0.8	_	pF
Resistance (input-output) (Note 7)	Rs	R.H. \leq 60 %, V _S = 1 kV _{DC}	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage (Note 7)	BVs	AC, 60 s	2500	_	_	V _{rms}

(Note 7) Device considered two-terminal device? Pins 1, 2, 3 and 4 shorted together and pin 5, 6, 7 and 8 shorted together.

Switching Characteristics (Ta = 25°C, Vcc = 5V)

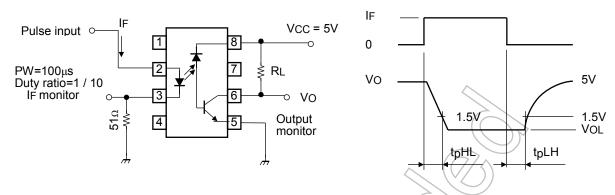
Characteristic	Symbol	Test Circuit.	Test Condition	Min	Тур.	Max	Unit
Propagation delay time			$I_F = 0 \rightarrow 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	_	0.3	0.8	
$(H \rightarrow L)$	tpHL		Rank O: R _L = 1.9 kΩ		0.5	0.8	μS
Propagation delay time (L→ H)	tpLH	1	$I_F = 16 \rightarrow 0$ mA, $V_{CC} = 5$ V, $R_L = 4.1$ k Ω) 1	2	
			Rank O; R _L = 1.9 kΩ	/	0.6	1.2	μS
Common mode transient immunity at high output level	Смн		I_F = 0 mA, V_{CM} = 200 V_{p-p} R_L = 4.1 kΩ (rank O: R_L = 1.9 kΩ) (Note 8)	_	1500	ı	V /μs
Common mode transient immunity at low output level	Смь		I_F = 16 mA, V_{CM} = 200 V_{p-p} R_L = 4.1 kΩ (rank O: R_L = 1.9 kΩ) (Note 8)	_	1500	\rightarrow	V /μs

(Note 8) CML is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (Vo < 0.8 V).

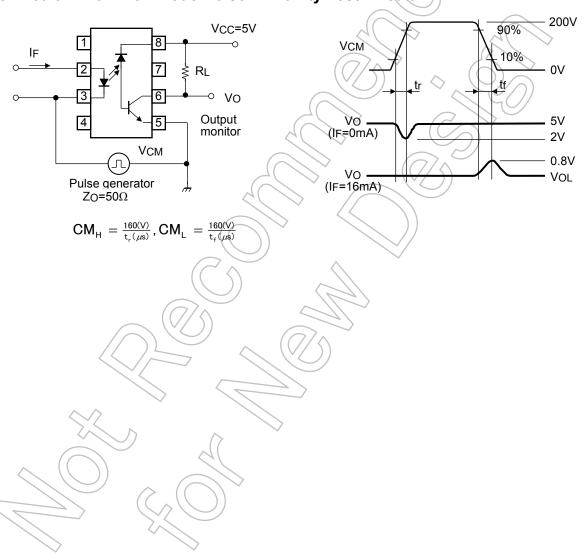
CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 2.0 \text{ V}$).

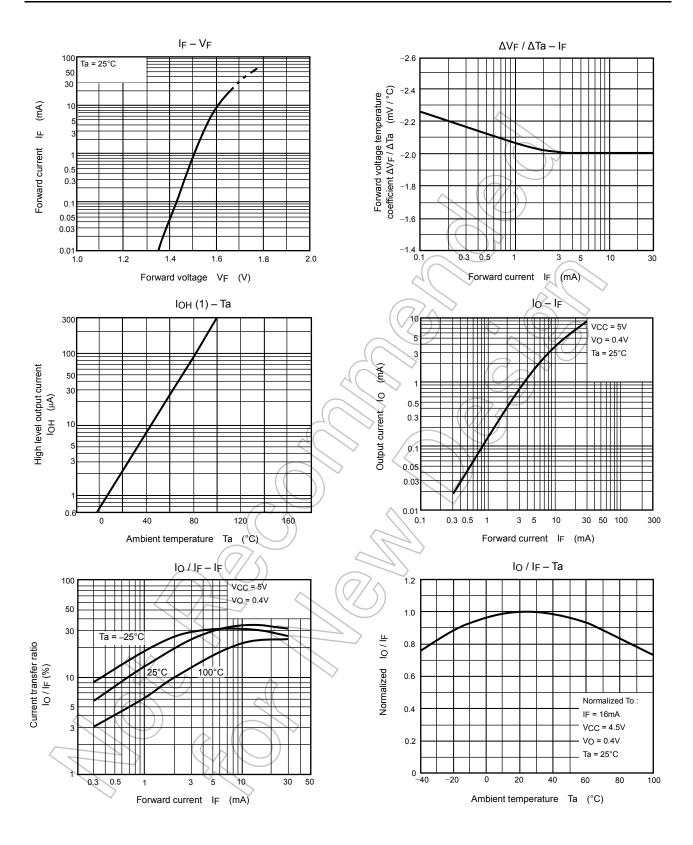


Test Circuit 1: Switching Time Test Circuit

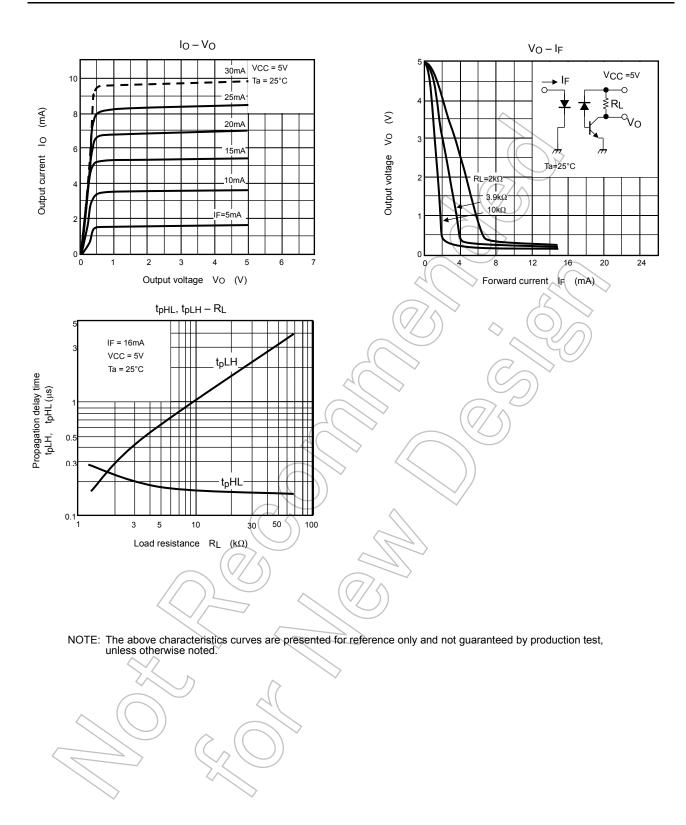


Test Circuit 2: Common Mode Noise Immunity Test Circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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